High-Precision Detection of Ordinary Sound by Electrospun Polyacrylonitrile Nanofibers

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Electronic Supplementary Information

Calculation of zigzag conformation content



Fig. S1. FTIR spectra of the PAN nanofiber membrane in the wavenumber range of 1205 cm⁻¹ to 1285 cm⁻¹.

The vibration bands at 1250 cm⁻¹ and 1230 cm⁻¹ were corresponded to zigzag conformation and 3^{1} -helical conformation, respectively. Based on the FTIR spectra, the zigzag conformation content (Φ) was estimated using the equation (S-1):

$$\Phi = S_{1250} / (S_{1250} + S_{1230}) \tag{S-1}$$

where S_{1250} and S_{1230} are the peaks at 1250 cm⁻¹ and 1230 cm⁻¹, respectively.

Calculation of β phase content



Fig. S2. FTIR spectra of the PVDF nanofiber membrane in the wavenumber range of 750 cm^{-1} to 850 cm^{-1} .

The FTIR spectrum showed characteristic vibration bands assigned to the PVDF β phases at 840 cm⁻¹ (CH₂ rocking and CF₂ asymmetrical stretching vibration) and 1276 cm⁻¹ (C-F stretching vibration). The characteristic bands associated with the α crystal phase were found at 613 cm⁻¹ (CF₂ bending and CCC skeletal vibration), 763 cm⁻¹ (CH₂ in-plane or rocking), and 975 cm⁻¹ (CH₂ twisting). Based on the FTIR result, the β phases content of PVDF can be calculated using the equation (S-2):

$$F(\beta) = A_{\beta} / (1.26 A_{\alpha} + A_{\beta})$$
 (S-2)

 A_{α} and A_{β} are the intensity of the β phase peak at 840 cm⁻¹ and the intensity of the α crystal phase peak at 763 cm⁻¹, respectively.



Fig. S3. (a) XRD pattern and (b) DSC curves of the PAN nanofiber membrane.



Fig. S4. Schematic illustration of the setup for testing the nanofiber devices.



Fig. S5. Effect of nanofiber membrane thickness on energy conversion performance under 200 Hz 115dB sound. The error bars represent the standard deviation obtained from the test results of at least three replicates.



Fig. S6. Effect of sound frequency on voltage signal outputs for (a) PAN and (b) PVDF under 115 dB sound. (Nanofiber membrane thickness, 30 μm)



Fig. S7. Effect of SPL on voltage signal outputs for the PAN and PVDF membranes under 200 Hz sound. (Nanofiber membrane thickness, $30 \mu m$)



Fig. S8. The linear dependency of voltage output (logarithmic coordinate) on SPL. (Nanofiber membrane thickness, $30 \mu m$)



Fig. S9. The accuracy analysis of the PAN sensor device in (a) 60-70 dB and (b) 90-95 dB. The accuracy analysis of the PVDF device (c) 60-70 dB and (d) 90-95 dB. (sound frequency 200Hz)



Fig. S10. The sensitivity of the PAN and PVDF nanofiber sensors at different (a) sound frequency (SPL, 75dB), and (b) SPL (sound frequency, 200Hz). (Membrane thickness, 30 µm)



Fig. S11. *L* value of the PAN and PVDF nanofiber sensors for the conversion of the sinusoidal sound wave at different conditions. (a) different sound frequencies (SPL, 75dB), and (b) different SPLs (sound frequency, 200Hz). (Membrane thickness, $30 \mu m$)



Fig. S12. Fitting of the voltage signals generated by the PAN nanofiber device for the input sound signal at the sound frequencies of (a) 100 Hz, (b) 150 Hz, (c) 200 Hz, (d) 250 Hz, (e) 300 Hz, (f) 350 Hz, (g) 400 Hz, (h) 500 Hz, and (i) 600 Hz. (SPL 75 dB; membrane thickness 30 μ m)



Fig. S13. Fitting of the voltage signals generated by the PVDF nanofiber device for the input sound signal at the sound frequencies of (a) 100 Hz, (b) 150 Hz, (c) 200 Hz, (d) 250 Hz, (e) 300 Hz, (f) 350 Hz, (g) 400 Hz, (h) 500 Hz, and (i) 600 Hz. (SPL 75 dB; membrane thickness 30 μ m)



Fig. S14. Fitting of the voltage signals generated by the PAN nanofiber device for the input sound signal at the sound pressure levels of (a) 60 dB, (b) 65 dB, (c) 70 dB, (d) 75 dB, (e) 80 dB, (f) 85 dB, (g) 90 dB, and (h) 95 dB. (Sound frequency 200 Hz, membrane thickness $30 \mu m$)



Fig. S15. Fitting of the voltage signals generated by the PVDF nanofiber device for the input sound signal at the sound pressure levels of (a) 60 dB, (b) 65 dB, (c) 70 dB, (d) 75 dB, (e) 80 dB, (f) 85 dB, (g) 90 dB, and (h) 95 dB. (Sound frequency 200 Hz, membrane thickness $30 \,\mu\text{m}$)



Fig. S16. The proposed nanofiber membrane deformation mechanism under sound.



Fig. S17. (a) Schematic illustration of nanomechanical testing apparatus (FemtoTools, FT-MTA03) for the dynamic mechanical analysis (DMA) of the nanofiber membranes; optical microscopic images obtained for (b) PAN nanofiber membrane and (c) PVDF nanofiber membrane (scale bars, $500 \mu m$).

The load presented a sine wave with a periodic frequency of 10 Hz. The load value was set ranging from 50 μ N to 200 μ N. The nanofiber membrane was subjected to a compressive impact at a certain frequency load, and the hysteresis of its displacement was recorded. The phase angle was obtained.



Fig. S18. The SEM image to show the PAN nanofibers after placing in 95 dB sound environment for 2 hours (scale bars, $2 \mu m$).



Fig. S19. The voltage signals after FFT band-filter process at 40-60 Hz for (a) PAN nanofiber device, (b) PVDF nanofiber device.



Fig. S20. (a) A digital photo to show the feasibility to be used as a flexible device.



Fig. S21. (A) voltage outputs, (B) sensitivity, and (c) fidelity of the PAN nanofiber device during 29 days of testing. (test condition: 200 Hz 75 dB sound, room temperature and humidity 20% - 30%)



Fig. S22. The sound sources covering the frequency range of 100 Hz-600 Hz in daily life activities ^[S-1-20].

Method	Principle	External power	Flexibility	Acoustoelectric conversion efficiency	Sensitivity	Signal-to-noise ratio
Electromagnetic	Electromagnetic induction under acoustic vibration	Required	Poor	High	High	High
Triboelectric	Generation of triboelectric charge under acoustic vibration	Self-powered	Good	High	High	High
Piezoelectric	Generation of piezoelectric charge under acoustic vibration	Self-powered	Good	High	High	High

 Table S1. Comparison of different types of acoustoelectric sensors

Matariala	Main work	Sound condition	V	Ι	Р	Dof
Iviaterials		Sound condition	(V)	(µA)	(µW)	Kel.
Electrospun PVDF nanofibers	Flexible all-nonwoven polymer-based piezoelectric generator	220 Hz, 105 dB	5.24	_	4.80	S-21
Electrospun PVDF nanofibers	Flexible sound energy device with the piezoelectric property improved	100 – 400 Hz,	0.0592		700	S-22
	by adding silver nanoparticles.	100 dB				
Electrospun PVDF nanofibers	A PVDF nanofiber generator based on different substrates.	100 Hz, 100 dB	0.778		_	S-23
Nanoporous PVDF arrays	Preparation of a nanoporous array of PVDF effective generator.	100 Hz, 100 dB	2.6	0.6	_	S-24
PVDF/ZnO composite nanofiber	An acoustoelectric nanogenerator using PVDF/ZnO composite fiber	140 Hz, 116 dB	1.12	1.6	1.792	S-25
membrane	membrane.					
PVDF film	Acoustic harvesting based on PVDF cantilever beams	146 Hz, 110 dB	1.48		2.2	S-26
PVDF film	A vibration energy harvesting generator based on a point-defect	510 Hz	0.0421		_	S-27
	photonic crystal with PVDF film.					
PVDF film	An energy harvesting based on PVDF cantilever beams and a Helmholtz	800 Hz	0.22		0.1	S-28
	resonator.					
PVDF/Graphene composite film	Preparation of a PVDF/graphene film acoustic harvesting device.	280 Hz, 105 dB	7.6			S-29

Table S2. A summary of the literature on piezoelectric PVDF for noise harvesting

Materials	Main work	Sound condition	S	F	SNR	Ref
	Wall work	Sound condition			(dB)	Ker.
Electrospun PVDF nanofibers	An acoustic sensor based on PVDF nanofiber membrane	220 Hz, 100 dB	266 mV/Pa	—	—	S-30
Electrospun PVDF nanofibers	An acoustic signal sensor that can obtain a wide resource of sound.	100 – 800 Hz		High		S-31
Electrospun PVDF nanofibers	All-nanofiber-based acoustic sensors that can monitor human	250 Hz, 110 dB	9.2 V/Pa	_	40.9	S-32
	motion.					
PVDF/ZnS composite nanofiber	An acoustoelectric sensor based on PVDF/ZnS composite fiber	86 Hz, 100 dB	3 V/Pa	_		S-33
membrane	web.					
PVDF film	An implantable microphone based on flexible PVDF film.	0.1 – 10 kHz,	20 mV/Pa	_	45	S-34
		50 – 60 dB				

Table S3. A summary of the literature on piezoelectric PVDF for sound sensors

Sound source				Sound sensing			
	f	SPL	Bandwidth	\mathbf{f}_{max}	S	F	L
	(Hz)	(dB)	(Hz)	(Hz)	(mV/Pa)		
PAN device		75	100 - 600	1200	-	-	-
		85	100 - 900	1800			
		95	100 - 2000	3000			
PVDF device		75	100 - 320	600	-	-	-
		85	100 - 400	800			
		95	100 - 550	1400			
PAN device	100 600	75			45.9 - 273.9	0.939 - 0.993	5.42% - 16.32%
PVDF device	100 - 000	75			12.2 - 161.5	0.873 - 0.941	14.52% - 29.43%
PAN device	200	60 05			271.5 - 351.9	0.938 - 0.995	4.3% - 17.82%
PVDF device	200	00 - 93			157 – 162.1	0.921 - 0.941	12.94% - 25.93%

Table S4. A comparison of sound detection properties between PAN and PVDF nanofiber devices

	$\frac{1}{m}\sum_{i=1}^{m}(V_{p-p})_i$	$2\sqrt[2]{\sum_{j=1}^{n} \frac{(V_{noise})_i^2}{n}}$	SNR (dB)
PAN device	34.3	0.6	57.2
PVDF device	22.7	0.6	37.8
Commercial microphone	88.2	1.7	51.9

 Table S5. SNR calculation results for the nanofiber devices and commercial microphone

Materials	Method	Sound condition	V (V)	Ι (μΑ)	S (mV/Pa)	SNR (dB)	F	Ref.
Ionogels	Resistive	100 Hz			24	50		S-35
		(underwater)						
PTFE nanowires-Cu	Triboelectric	110 Hz, 144.2 dB	65	32				S-36
		(underwater)						
PTFE nanowires-nylon	Triboelectric	A human voice of			51			S-37
		"one word"						
PTFE film-silver	Triboelectric	200 – 1850 Hz	pprox 0.1 - 0.6			_	_	S-38
PTFE nanowires-Al	Triboelectric	240 Hz, 70 dB	0.73	0.19	11542.3	_	_	S-39
PTFE nanowires-Cu	Triboelectric	250 Hz, 114 dB	≈ 45	≈ 17	≈ 4489.3			S-40
FEP film-Au	Triboelectric	100 dB	1.2		600			S-41
PVDF-TrFE nanofibers	Piezoelectric	250 Hz, 90 dB	0.2		316.2			S-42
PVDF-TrFE nanofibers	Piezoelectric	100 – 400 Hz, 78 dB	0.001 - 0.017		6.3 – 107	_	_	S-43
PVDF-TrFE film	Piezoelectric	110 dB	≈ 0.4		≈ 63.2	_	_	S-11
PZT film	Piezoelectric	250 Hz, 94 dB	0.012		12		_	S-44
BZT-BCT nanofibers	Piezoelectric	126 Hz, 104 dB	1.0	0.132	315.5			S-45

Table S6. A summary of of acoustoelectric sensors made of different materials

Ref.	Materials	Device structure	Main innovation	Sound condition	Key results reported
Nature Communications, 2016, 7, 11108	PVDF	Single hole	First time to report the sound sensing properties of the PVDF nanofiber membrane.	220 Hz, 100 dB	S = 266 mV/Pa
Nano Energy, 2020, 75, 104956	PAN	8 holes	First time to report the application of electrospun PAN nanofiber membrane for harvesting noise.	100 – 500 Hz, 117 dB	$V = 58 V$ $I = 12 \mu A$
This work	PAN	Single hole	The first time to report the use of electrospun PAN nanofiber membrane as a sound sensor to detecting middle-intensity sounds. First time to compare the sensing properties between PAN and PVDF nanofiber membranes for application as sound sensors for voice recognition applications.	100 – 600 Hz, 60 – 95 dB	S = 45.9 – 273.9 mV/Pa F = 0.938 – 0.995 SNR = 57.2 dB

Table S7. The main differences between current work and our	r previous pape	rs [S-30, 46]
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f = Frequency, SPL = Sound pressure level, V = Voltage output, I = Current output, P = Power output on an optimized load, $f_{max} = Maximum$ response frequency, S = Sensitivity, F = Fidelity, L = maximum loss ratio, SNR = Signal to noise ratio

Supplementary Videos

Audio S1: the playing effect of the electrical signal recorded by the PAN nanofiber device from a short section of "*high mountains and flowing water*".

Audio S2: the playing effect of the electrical signal recorded by the PVDF nanofiber device from a short section of "*high mountains and flowing water*".

Audio S3: the original signal of "high mountains and flowing water".

Audio S4: the playing effect of the electrical signal recorded by the PAN nanofiber device from a short section of *"high mountains and flowing water"* in a high noise environment.

Audio S5: the original signal of "high mountains and flowing water" in a high noise environment.

Audio S6: the playing effect of the electrical signal recorded by the PAN nanofiber device from a human voice of "*Hello*".

Audio S7: the original signal of a human voice of "Hello".

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